Silicon Bridge Rectifiers



KBP200 Thru 2010

Reverse Voltage: 50 - 1000 Volts

Forward Current: 2.0 Amp

Features

Diffused Junction

Low Forward Voltage Drop

High Current Capability

High Reliability

High Surge Current Capability

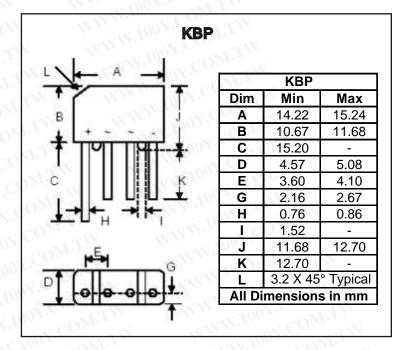
Ideal for Printed Circuit Boards

Mechanical Data

Case: Molded Plastic

Terminals: Plated Leads Solderable per

MIL-STD-202, Method 208 Weight: 1.7 grams (approx.) Mounting Position: Any Marking: Type Number



Maximum Ratings and Electrical Characterics

Single Phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

CHARACTERISTICS	Symbol	KBP 200	KBP 201	KBP 202	KBP 204	KBP 206	KBP 208	KBP 2010	UNIT
Peak Repetitive Reverse Voltage	V_{RRM}	WW	100	I.Con	WT		MM	100X	
Working Peak Reverse Voltage	V_{RWM}	50	100	200	400	600	800	1000	$\mathbb{C}V^{\mathbb{N}}$
DC Blocking Voltage	V_{R}		VW.10	×1 CC	$M_{1,T}$	J	-XIVV	W.700	V.CO
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectified Output Current @ $T_A = 50$ °C (Note 1)			WWW.	100 X	2.0	TW	N.	WW.10	AC
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rate load (JEDEC Method)	I _{FSM}	Į	MM	W.100Y	60	TW WT		MMM	10A
Forward Voltage (per element) @I _F = 2.0A	V_{FM}	XI.	-111	Mila	1.1	NY.			V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _{RM}		W	WW.10	10 500	$\mathcal{M}_{T,T}$			uA
Rating for Fusing (t<8.3ms)	$ I^2$ t	-XX	×	MW.	15				A^2s
Typical Junction Capacitance per element (Note 2)	Cj	25							pF
Typical Thermal Resistance (Note 3)	R _{eJA}	TI	•		30	•	•		K/W
Operating and Storage Temperature Range	Tj, T _{STG}	_		-:	55 to +16	60		_	°C

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

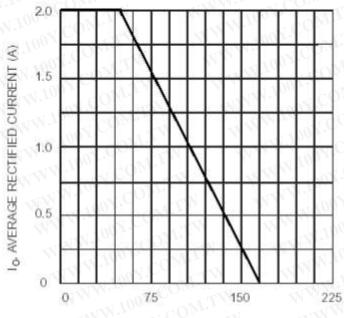
- 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
- 3. Thermal resistance junction to ambient mounted on PC board with 12mm² copper pad.

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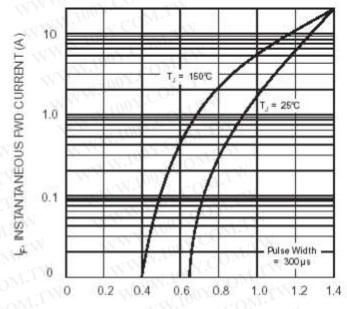
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T, TEMPERATURE ("C)
Fig. 1 Forward Current Derating Curve



V_F, INSTANTANEOUS FWD VOLTAGE (V) Fig. 2 Typical Fwd Characteristics

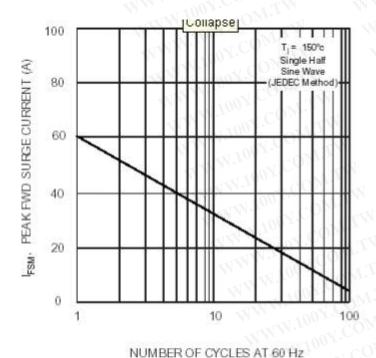
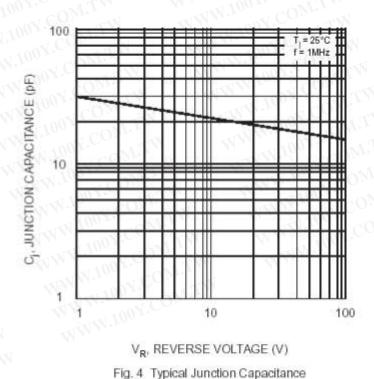


Fig. 3 Max Non-Repetitive Peak Fwd Surge Current



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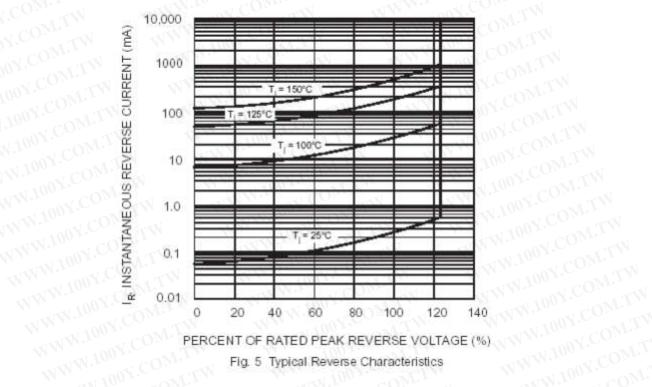
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Rating and Characteristic Curves (KBP200 - KBP2010)



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